

40V PNP LOW VCESAT TRANSISTOR IN PowerDI3333-8

Features

- BV_{CEO} > -40V
- Small Form Factor Thermally Efficient Package.
 Enables Higher Density End Products
- I_C = -2A Continuous Collector Current
- I_{CM} = -3A Peak Pulse Current
- Low Saturation Voltage V_{CE(sat)} < -225mV @ -1A
- Complementary NPN Type: DXTN22040CFGQ
- Rated to +175°C Ideal For High Temperature Environment
- Wettable Flank For Improved Optical Inspection
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DXTP22040CFGQ is suitable for automotive applications requiring specific change control and is AEC-Q101 qualified, is PPAP capable, and is manufactured in IATF16949:2016 certified facilities.

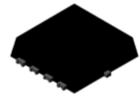
Mechanical Data

- Case: PowerDI[®]3333-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.03 grams (Approximate)

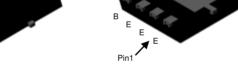
Applications

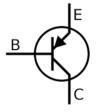
- High-Side Switch
- Supply Line Switching
- Motor Driving

PowerDI3333-8 (SWP) (Type UX)



Top View





Device Symbol

Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
DXTP22040CFGQ-7	Automotive	2K3	7	12	2,000

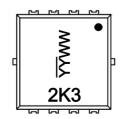
Bottom View

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information

PowerDI3333-8 (SWP) (Type UX)



2K3 = Product Type Marking Code

YWWW = Date Code Marking

YY = Last Two Digits of Year (ex: 19 = 2019)

WW = Week Code (01 to 53)



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Collector-Base Voltage	V_{CBO}	-50	V	
Collector-Emitter Voltage	V _{CEO}	-40	V	
Emitter-Base Voltage	V _{EBO}	-7	V	
Continuous Collector Current	I _C	-2	۸	
Peak Pulse Collector Current	I _{CM}	-3	A	
Continuous Base Current	Ι _Β	-100	mΛ	
Peak Pulse Base Current	I _{BM}	-200	- mA	

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
	(Note 5)		1.07	W
Power Dissipation	(Note 6)	P _D	2.3	W
	(Note 7)		3.4	W
	(Note 5)		140	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	R _{θJA}	65	°C/W
	(Note 7)		44	°C/W
Thermal Resistance, Junction to Leads (Note 8	R _{0JL}	11	°C/W	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +175	°C	

ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge – Machine Model	ESD MM	400	V	С

Notes: 5. For a device mounted with the collector tab on MRP FR4-PCB; device is measured under still air conditions whilst operating in a steady-state.

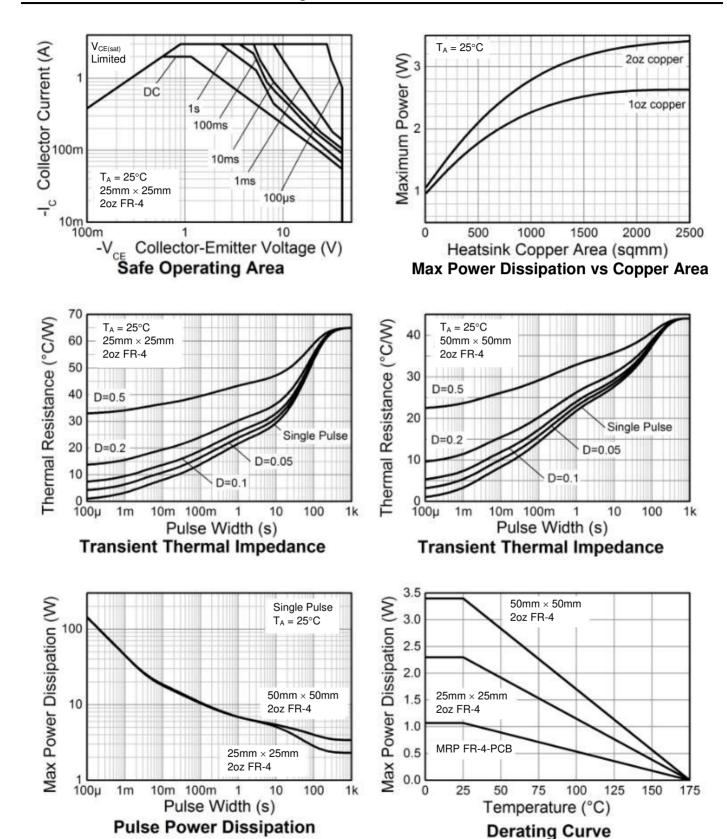
- 6. Same as Note 5, except the device is mounted on 25mm × 25mm 2oz copper.
- 7. Same as Note 5, except the device is mounted on 50mm × 50mm 2oz copper.

 8. Thermal resistance from junction to solder-point (at the collector tab).

 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





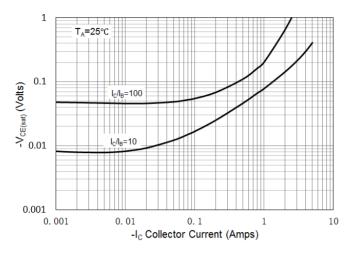
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

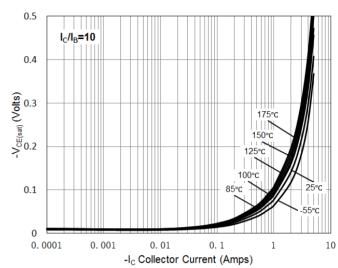
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-50	-71	_	V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	-40	-50	_	V	$I_C = -10mA$
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8.6	_	V	$I_E = -100\mu A$
Collector-Base Cut-Off Current	I _{CBO}	1	-1 -0.1	-20 -10	nA μA	V _{CB} = -50V V _{CB} = -40V, T _A = +150°C
Emitter-Base Cut-Off Current	I _{EBO}		-1	-20	nA	V _{EB} = -6V
Collector-Emitter Cut-Off Current	I _{CES}	_	-1	-20	nA	$V_{CE} = -40V, V_{BE} = 0V$
Static Forward Current Transfer Ratio (Note 10)	h _{FE}	200 200 150 80	340 299 261 196	600 — —		I _C = -100mA, V _{CE} = -2V I _C = -500mA, V _{CE} = -2V I _C = -1A, V _{CE} = -2V I _C = -2A, V _{CE} = -2V
Collector-Emitter Saturation Voltage (Note 10)	V _{CE(sat)}	-	-52 -42 -71 -129 -189-	-100 -130 -225 -350 -600	mV	$\begin{split} &I_{C} = -100\text{mA}, \ I_{B} = -1\text{mA} \\ &I_{C} = -500\text{mA}, \ I_{B} = -50\text{mA} \\ &I_{C} = -1\text{A}, \ I_{B} = -100\text{mA} \\ &I_{C} = -2\text{A}, \ I_{B} = -200\text{mA} \\ &I_{C} = -3\text{A}, \ I_{B} = -300\text{mA} \end{split}$
Collector-Emitter Saturation Resistance (Note 10)	R _{CE(sat)}		_	225	mΩ	$I_C = -1A$, $I_B = -100mA$
Base-Emitter Saturation Voltage (Note 10)	V _{BE(sat)}		-0.88	-1	V	$I_C = -1A$, $I_B = -100mA$
Base-Emitter Turn-On Voltage (Note 10)	V _{BE(on)}	_	-0.77	-0.9	V	$I_C = -1A$, $V_{CE} = -2V$
Transition Frequency	f⊤	_	120	_	MHz	$I_C = -50 \text{mA}, V_{CE} = -10 \text{V}$ f = 100MHz
Output Capacitance	C _{obo}	_	12	_	pF	$V_{CB} = -10V$, $f = 1MHz$
	t _{delay}		11.6	_	ns	
Switching Characteristics	t _{rise}	_	128	_	ns	$V_{CC} = -10V, I_{C} = -500mA$
Owitering Oriandelensiles	tstorage		524	_	ns	$I_{B1} = -I_{B2} = -50 \text{mA}$
	t _{fall}	_	69.4	_	ns	

Note: 10. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.



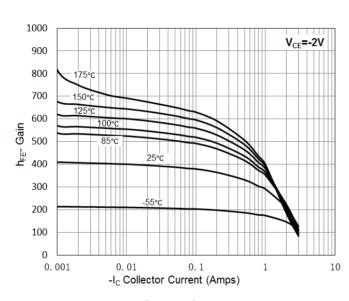
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

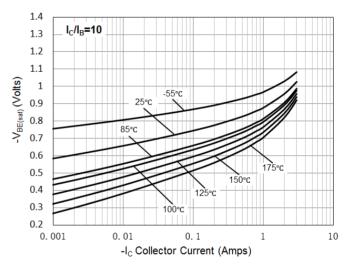




 $V_{\text{CE(sat)}}vs I_{\text{C}}$

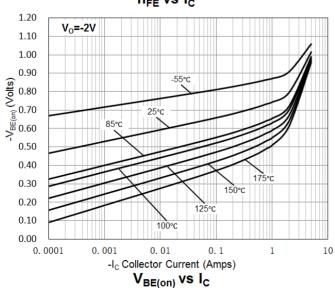






h_{FE} vs I_C

V_{BE(sat)} vs I_C

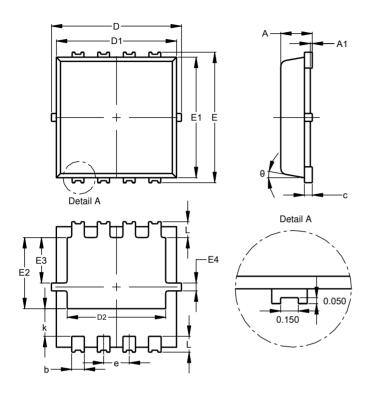




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)

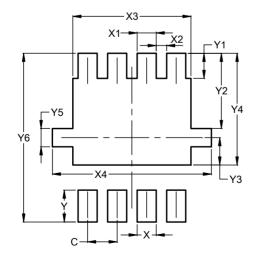


PowerDI3333-8 (SWP)				
(Type UX)				
Dim	Min	Max	Тур	
Α	0.75	0.85	0.80	
A1	0.00	0.05		
b	0.25	0.40	0.32	
С	0.10	0.25	0.15	
D	3.20	3.40	3.30	
D1	2.95	3.15	3.05	
D2	2.30	2.70	2.50	
E	3.20	3.40	3.30	
E1	2.95	3.15	3.05	
E2	1.60	2.00	1.80	
E3	0.95	1.35	1.15	
E4	0.10	0.30	0.20	
е	_	_	0.65	
k	0.50	0.90	0.70	
L	0.30	0.50	0.40	
θ	0°	12°	10°	
All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (SWP) (Type UX)



Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	0.420
X2	0.230
Х3	2.600
X4	3.500
Υ	0.700
Y1	0.550
Y2	1.650
Y3	0.600
Y4	2.450
Y5	0.400
Y6	3.700



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